

EUROPEAN PATENT OFFICE

Patent Abstracts of Japan

PUBLICATION NUMBER : 11026706
PUBLICATION DATE : 29-01-99

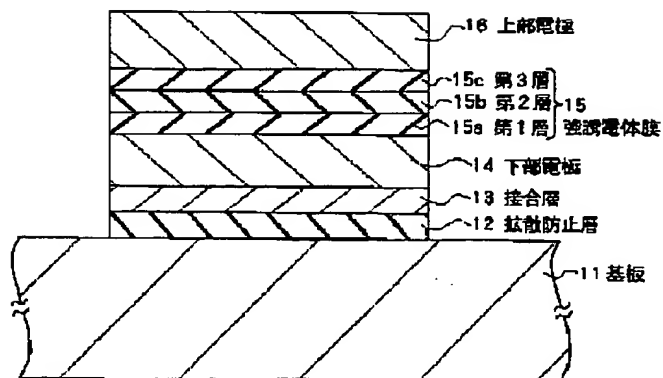
APPLICATION DATE : 09-07-97
APPLICATION NUMBER : 09184147

APPLICANT : SONY CORP;

INVENTOR : TANAKA NAOHIRO;

INT.CL. : H01L 27/10 H01L 27/04 H01L 21/822
H01L 27/108 H01L 21/8242 H01L
21/8247 H01L 29/788 H01L 29/792 //
H01L 21/316

TITLE : FERROELECTRIC CAPACITOR AND
MANUFACTURE THEREOF, AND
MEMORY CELL THEREWITH



ABSTRACT : PROBLEM TO BE SOLVED: To miniaturize a device by reducing the size of crystal grains while maintaining excellent ferroelectric characteristics.

SOLUTION: A lower electrode 14, a ferroelectric film 15 and an upper electrode are formed on a substrate 11. The ferroelectric film 15 is laminated with a plurality of layers 15a, 15b and 15c containing polycrystalline lamellar crystal structure oxide ($\text{Bi}_x(\text{Sr}, \text{Ca}, \text{Ba})_y(\text{Ta}, \text{Nb})_2\text{O}_{9\pm d}$) and divided each other. In this case, at least one layer of the layers 15a, 15b and 15c has different (Sr, Ca, Ba) component ratio y from other layers. In other words, (Sr, Ca, Ba) component ratio y of the ferroelectric film 15 is made to change. Thereby, the size of the crystal grains in the lamellar crystal structure oxide is reduced while excellent ferroelectric characteristics is obtained.

COPYRIGHT: (C)1999,JPO